

FGW75N60H

Discrete IGBT

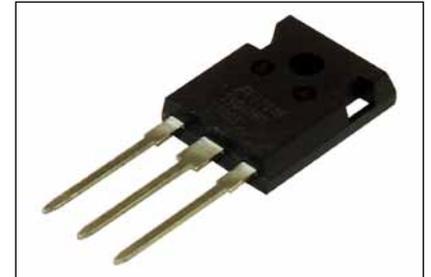
Discrete IGBT (High-Speed V series) 600V / 75A

■ Features

- Low power loss
- Low switching surge and noise
- High reliability, high ruggedness (RBSOA, SCSOA etc.)

■ Applications

- Uninterruptible power supply
- Power conditioner
- Power factor correction circuit



■ Maximum Ratings and Characteristics

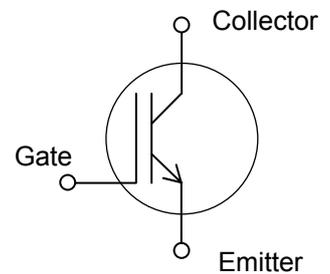
● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter Voltage	V _{CEs}	600	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
DC Collector Current	I _{C@25}	100	A	T _c =25°C, T _j =150°C Note *1
	I _{C@100}	75	A	T _c =100°C, T _j =150°C
Pulsed Collector Current	I _{CP}	225	A	Note *2
Turn-Off Safe Operating Area	-	225	A	V _{CE} ≤600V, T _j ≤175°C
Short Circuit Withstand Time	t _{SC}	5	μs	V _{CC} ≤300V, V _{GE} =12V T _j ≤150°C
Maximum Power Dissipation	P _D	500	W	T _c =25°C
Operating Junction Temperature	T _j	-40 ~ +175	°C	
Storage Temperature	T _{stg}	-55 ~ +175	°C	

Note *1 : Current value limited by bonding wire.

Note *2 : Pulse width limited by T_{jmax}.

■ Equivalent circuit



● Electrical characteristics (at T_j= 25°C unless otherwise specified)

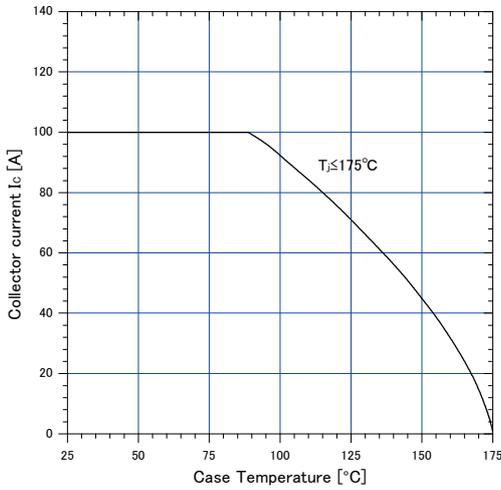
Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Collector-Emitter Breakdown Voltage	V _{(BR)CES}	I _c = 250μA, V _{GE} = 0V	600	-	-	V	
Zero Gate Voltage Collector Current	I _{CES}	V _{CE} = 600V, V _{GE} = 0V	T _j =25°C	-	-	250	μA
			T _j =175°C	-	-	10	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} = 0V, V _{GE} = ±20V	-	-	200	nA	
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{CE} = +20V, I _c = 75mA	4.0	5.0	6.0	V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} = +15V, I _c = 75A	T _j =25°C	-	1.50	1.95	V
			T _j =175°C	-	1.80	-	
Input Capacitance	C _{ies}	V _{CE} =25V	-	6150	-	pF	
Output Capacitance	C _{oes}	V _{GE} =0V	-	300	-		
Reverse Transfer Capacitance	C _{res}	f=1MHz	-	240	-		
Gate Charge	Q _G	V _{CC} = 400V I _c = 75A V _{GE} = 15V	-	460	-	nC	
Turn-On Delay Time	t _{d(on)}	T _j = 25°C	-	45	-	ns	
Rise Time	t _r	V _{CC} = 400V	-	130	-		
Turn-Off Delay Time	t _{d(off)}	I _c = 75A	-	450	-		
Fall Time	t _f	V _{GE} = 15V	-	105	-		
Turn-On Energy	E _{on}	R _G = 10Ω	-	3.0	-	mJ	
Turn-Off Energy	E _{off}	L = 500μH Energy loss include "tail" and FWD (FDRW35S60L) reverse recovery.	-	4.2	-		
Turn-On Delay Time	t _{d(on)}	T _j = 175°C	-	45	-	ns	
Rise Time	t _r	V _{CC} = 400V	-	130	-		
Turn-Off Delay Time	t _{d(off)}	I _c = 75A	-	490	-		
Fall Time	t _f	V _{GE} = 15V	-	120	-		
Turn-On Energy	E _{on}	R _G = 10Ω	-	4.3	-	mJ	
Turn-Off Energy	E _{off}	L = 500μH Energy loss include "tail" and FWD (FDRW35S60L) reverse recovery.	-	4.8	-		

● Thermal resistance characteristics

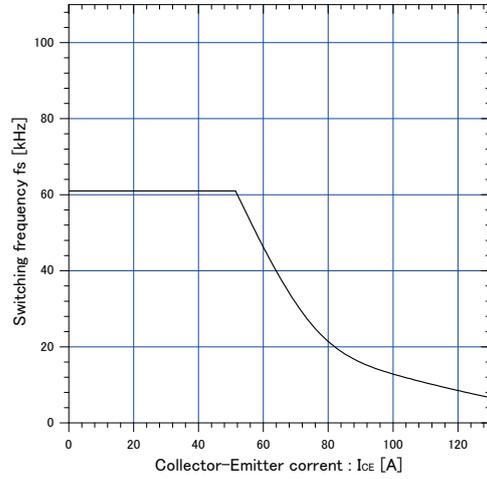
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal Resistance, Junction-Ambient	R _{th(j-a)}	-	-	-	50	°C/W
Thermal Resistance, Junction to Case	R _{th(j-c)}	-	-	-	0.298	

■ Characteristics (Representative)

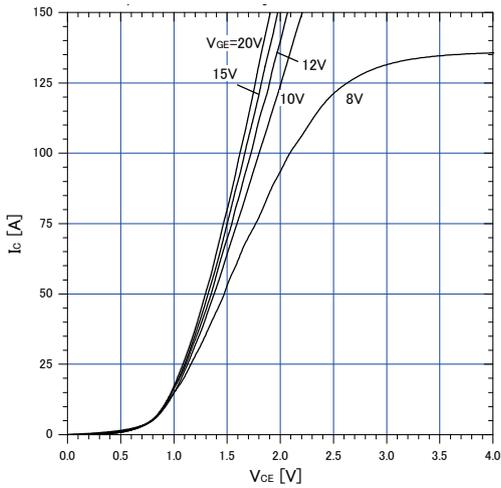
Graph.1
DC Collector Current vs T_c
 $V_{GE} \geq +15V, T_j \leq 175^\circ C$



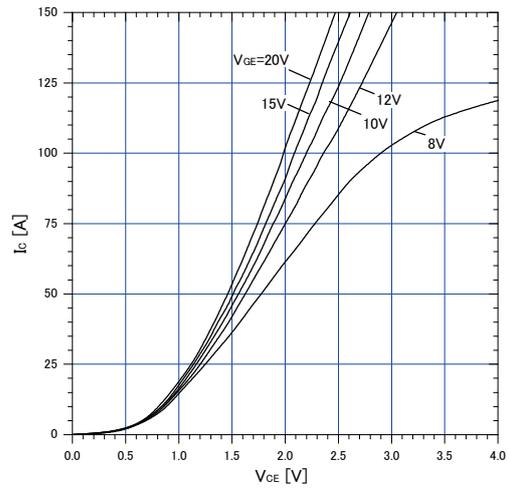
Graph.2
Collector Current vs. switching frequency
 $V_{GE} = +15V, T_c \leq 175^\circ C, V_{CC} = 400V, D = 0.5, R_G = 10\Omega, T_c = 100^\circ C$



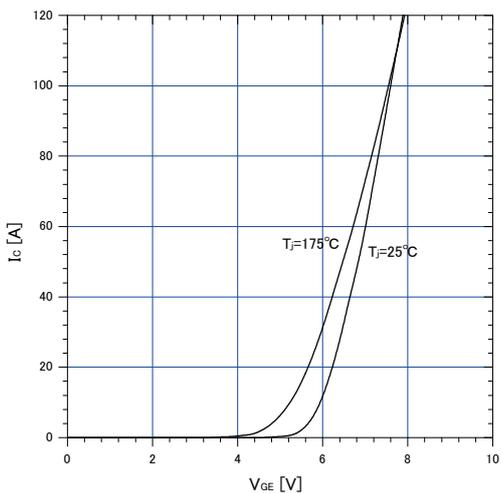
Graph.3
Typical Output Characteristics ($V_{CE}-I_c$)
 $T_j = 25^\circ C$



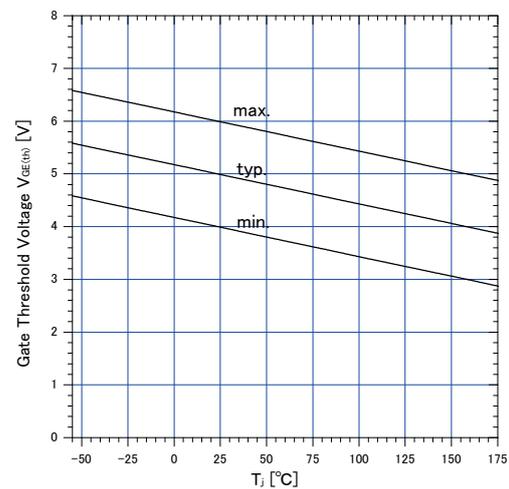
Graph.4
Typical Output Characteristics ($V_{CE}-I_c$)
 $T_j = 175^\circ C$



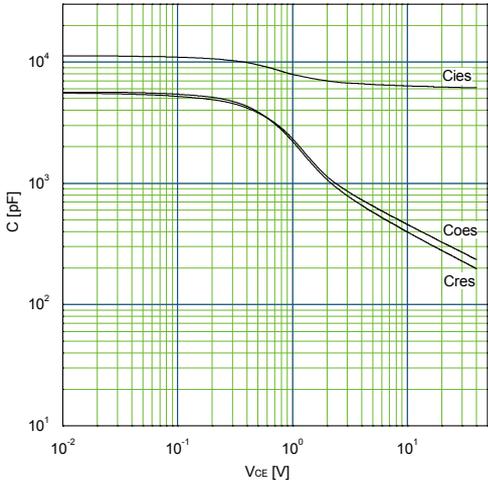
Graph.5
Typical Transfer Characteristics
 $V_{GE} = +15V$



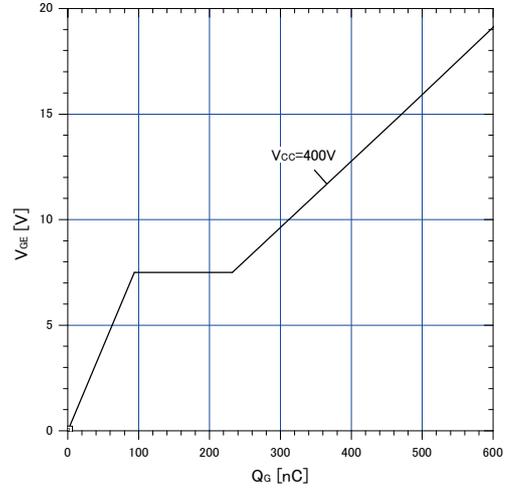
Graph.6
Gate Threshold Voltage vs. T_j
 $I_c = 75mA, V_{CE} = 20V$



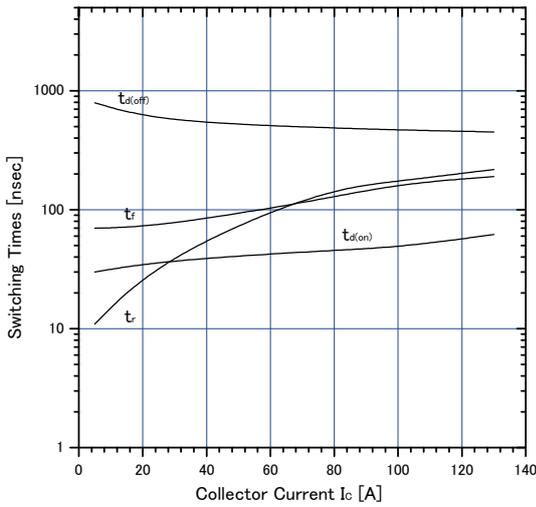
Graph.7
Typical Capacitance
 $V_{GE}=0V, f=1MHz, T_J=25^{\circ}C$



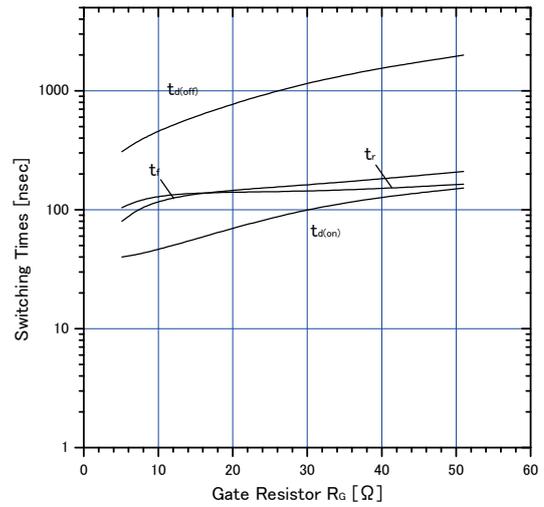
Graph.8
Typical Gate Charge
 $V_{CC}=400V, I_c=75A, T_J=25^{\circ}C$



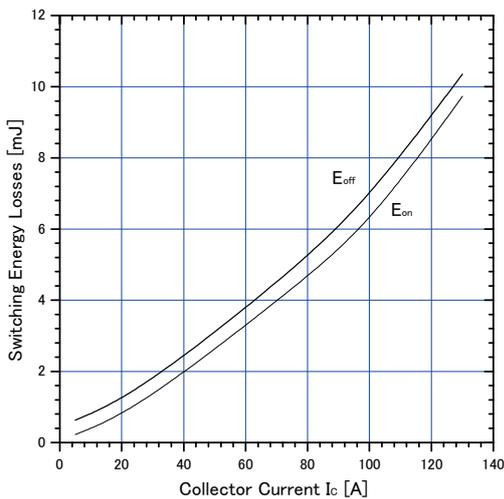
Graph.9
Typical switching time vs. I_c
 $T_J=175^{\circ}C, V_{CC}=400V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



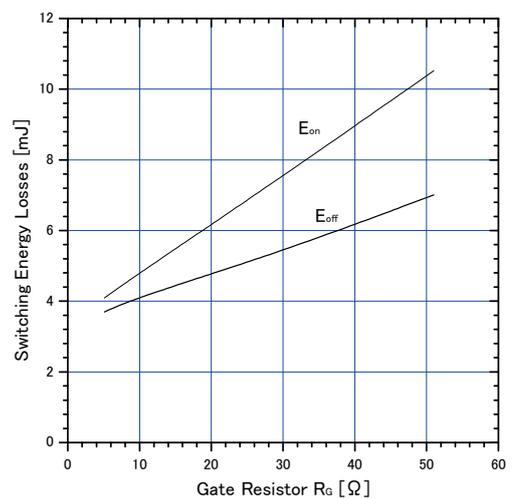
Graph.10
Typical switching time vs. R_G
 $T_J=175^{\circ}C, V_{CC}=400V, I_c=75A, L=500\mu H$
 $V_{GE}=15V$



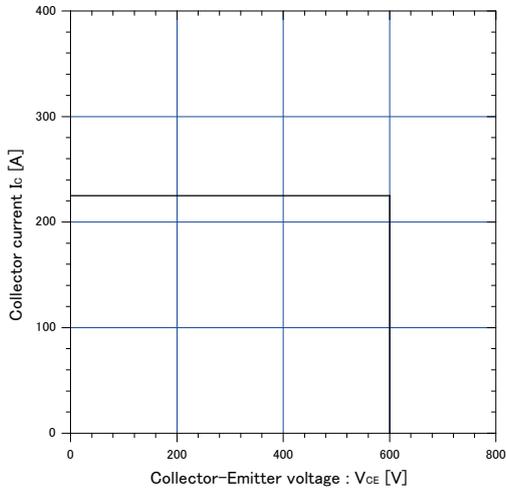
Graph.11
Typical switching losses vs. I_c
 $T_J=175^{\circ}C, V_{CC}=400V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



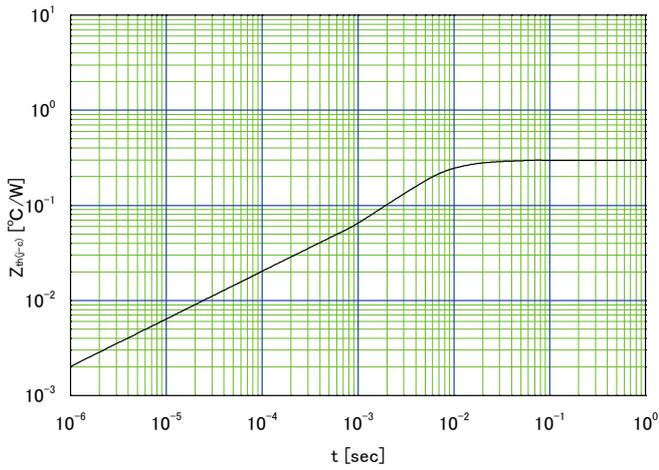
Graph.12
Typical switching losses vs. R_G
 $T_J=175^{\circ}C, V_{CC}=400V, I_c=75A, L=500\mu H$
 $V_{GE}=15V$



Graph.13
Reverse biased Safe Operating Area
 $T_j \leq 175^\circ\text{C}, V_{GE} = +15\text{V}/0\text{V}, R_G = 10\Omega$

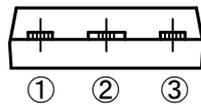
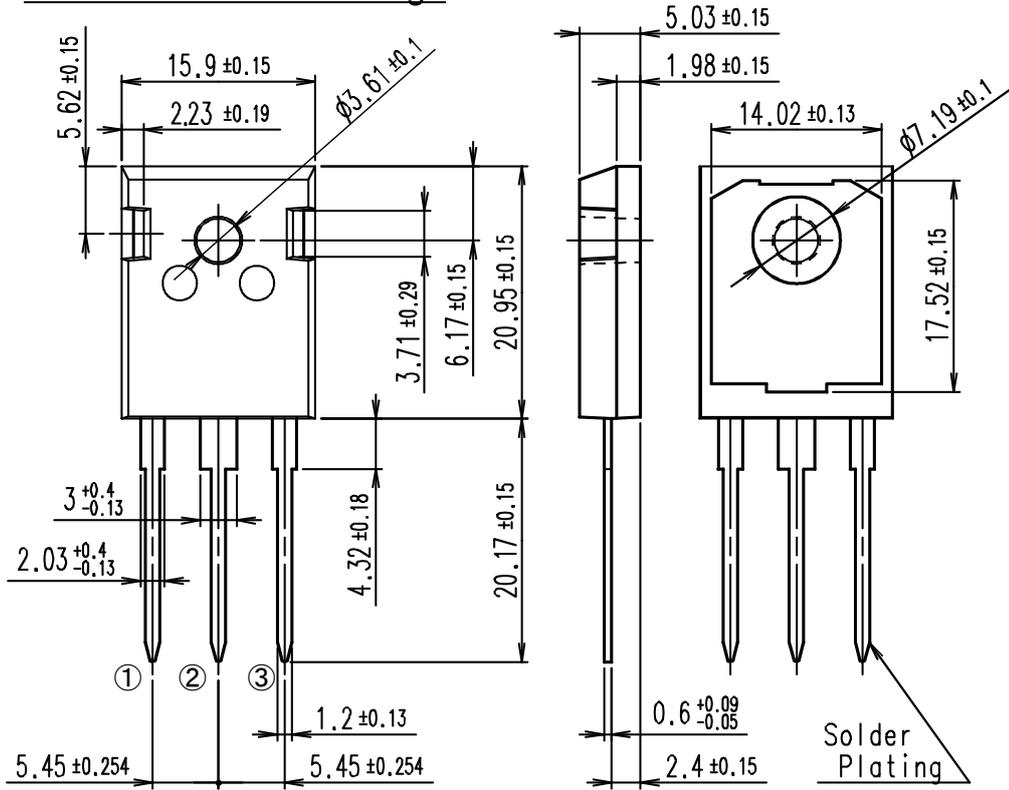


Graph.14
Transient thermal resistance of IGBT



■ Outline Drawings, mm

Outview : TO-247 Package



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